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BLF8G27LS-140

Power LDMOS transistor

AMPLEON

Rev. 3 — 1 September 2015

Product data sheet

1. Product profile

1.1 General description

140 W LDMOS power transistor for base station applications at frequencies from 2500 MHz to 2700 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in a common source class-AB production test circuit.

Test signal	f	I _{Dq}	V _{DS}	P _{L(AV)}	Gp	η_{D}	ACPR
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
2-carrier W-CDMA	2600 to 2700	1300	32	45	17.4	32	-30 ^[1]
2-carrier W-CDMA	2600 to 2700	1300	28	35	17.0	29	-31 <u>[1]</u>

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 8.4 dB at 0.01 % probability on CCDF; carrier spacing 5 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

■ RF power amplifier for W-CDMA base stations and multi carrier applications in the 2500 MHz to 2700 MHz frequency range

2. Pinning information

Table 2. Pinning

Description	Simplified outline	Graphic symbol
drain		_
gate		, _
source	[1]	2 — 3 3 sym112
	gate	gate 1 3

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package			
	Name	Description	Version	
BLF8G27LS-140	-	earless flanged ceramic package; 2 leads	SOT502B	

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V _{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		<u>[1]</u> _	225	°C

^[1] Continuous use at maximum temperature will affect the reliability.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 55 W	0.27	K/W

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.16 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 216 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 28 V	-	-	4.5	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 10 V$	-	40	-	Α
I _{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	450	nA
9fs	forward transconductance	V_{DS} = 10 V; I_{D} = 10.8 A	-	16	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 7.56 \text{ A}$	-	0.06	-	Ω

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR 8.4 dB at 0.01 % probability on CCDF; 3GPP test model 1; 64 DPCH; f_1 = 2622.5 MHz; f_2 = 2627.5 MHz; f_3 = 2682.5 MHz; f_4 = 2687.5 MHz; RF performance at V_{DS} = 32 V; I_{Dq} = 1300 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 45 W$	15.8	17.4	-	dB
RLin	input return loss	$P_{L(AV)} = 45 W$	-	-18	-8	dB
η_{D}	drain efficiency	$P_{L(AV)} = 45 W$	27	32	-	%
ACPR _{5M}	adjacent channel power ratio (5 MHz)	P _{L(AV)} = 45 W	-	-30	-27	dBc

7. Test information

7.1 Ruggedness in class-AB operation

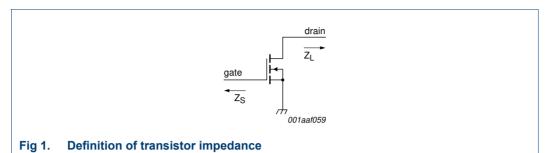
The BLF8G27LS-140 is capable to withstand a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 1300 mA; P_L = 180 W (CW); f = 2620 MHz.

7.2 Impedance information

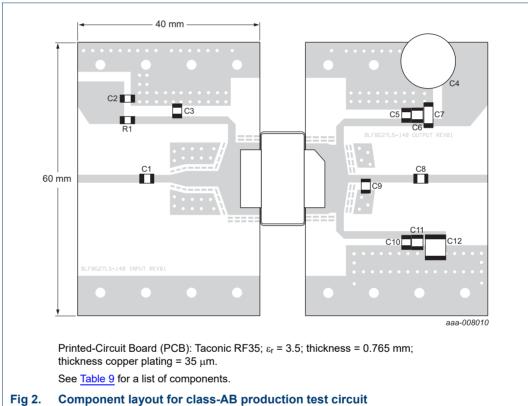
Table 8. Typical impedance $I_{Dq} = 1300 \text{ mA}$; $V_{DS} = 32 \text{ V}$.

f	Z _S [1]	Z <u>L^[1]</u>
(MHz)	(Ω)	(Ω)
2600	2.30 - j4.90	1.40 – j3.10
2700	3.80 – j4.50	1.40 – j3.10

[1] Z_S and Z_L defined in Figure 1.



7.3 Test circuit



- 19 21 Component layout 101 Class 712 production toot chous

Table 9. List of components

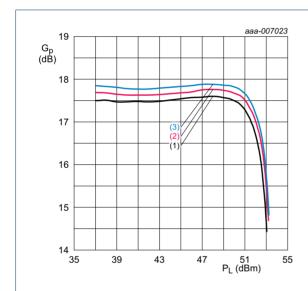
For test circuit see Figure 2.

Component	Description	Value		Remarks
C1, C3, C5, C8, C10	multilayer ceramic chip capacitor	10 pF	[1]	ATC100B
C2	multilayer ceramic chip capacitor	1 μF, 25 V	[2]	Murata
C4	electrolytic capacitor	470 μF, 63 V		
C6, C11	multilayer ceramic chip capacitor	1 μF, 50 V	[2]	Murata
C7, C12	multilayer ceramic chip capacitor	10 μF, 50 V	[2]	Murata
C9	multilayer ceramic chip capacitor	0.5 pF	[1]	ATC100B
R1	chip resistor	3.9Ω , 1% tolerance		Philips SMD 1206

- [1] American Technical Ceramics type 100B or capacitor of same quality.
- [2] Murata or capacitor of same quality.

7.4 Graphical data

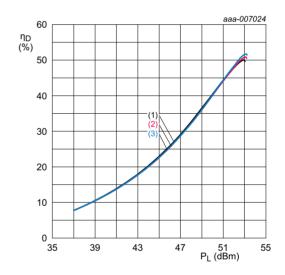
7.4.1 Pulsed CW



 V_{DS} = 32 V; I_{Dq} = 1300 mA; f = 860 MHz; t_p = 100 μs ; δ = 10 %.

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

Fig 3. Power gain as a function of output power; typical values

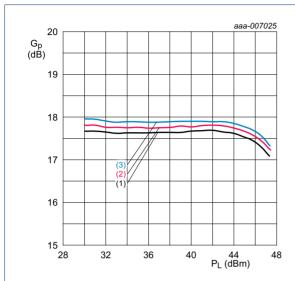


 V_{DS} = 32 V; I_{Dq} = 1300 mA; f = 860 MHz; t_p = 100 μs ; δ = 10 %.

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

Fig 4. Drain efficiency as a function of output power; typical values

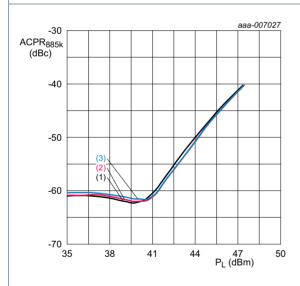
7.4.2 IS-95



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

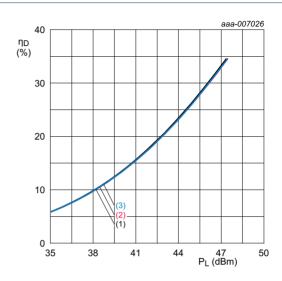
Fig 5. Power gain as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

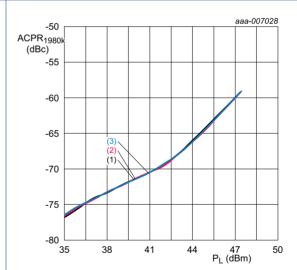
Fig 7. Adjacent channel power ratio (885 kHz) as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

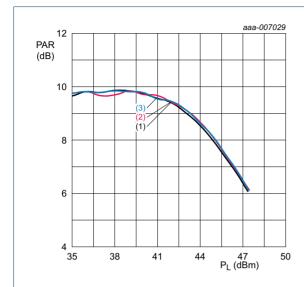
Fig 6. Drain efficiency as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

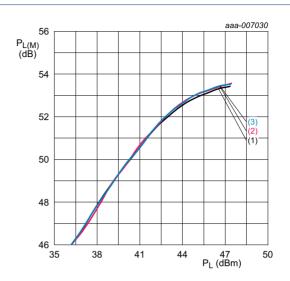
Fig 8. Adjacent channel power ratio (1980 kHz) as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

Fig 9. Peak-to-average power ratio as a function of output power; typical values

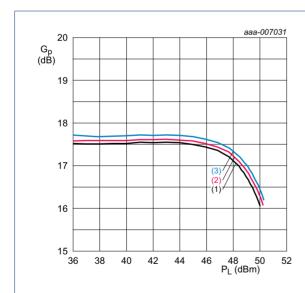


 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2620 MHz
- (2) f = 2655 MHz
- (3) f = 2690 MHz

Fig 10. Peak output power as a function of output power; typical values

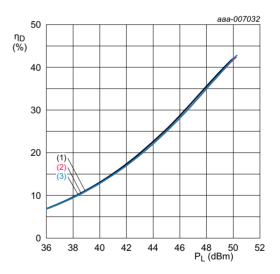
7.4.3 1-Carrier W-CDMA



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2622.5 MHz
- (2) f = 2655 MHz
- (3) f = 2687.5 MHz

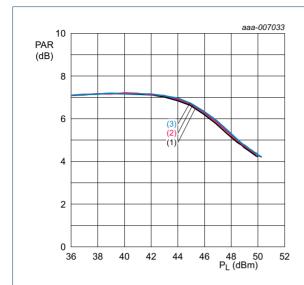
Fig 11. Power gain as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2622.5 MHz
- (2) f = 2655 MHz
- (3) f = 2687.5 MHz

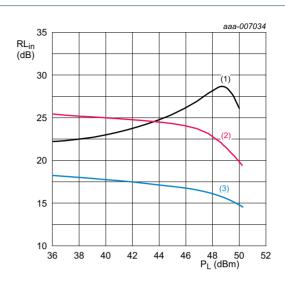
Fig 12. Drain efficiency as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2622.5 MHz
- (2) f = 2655 MHz
- (3) f = 2687.5 MHz

Fig 13. Peak-to-average power ratio as a function of output power; typical values

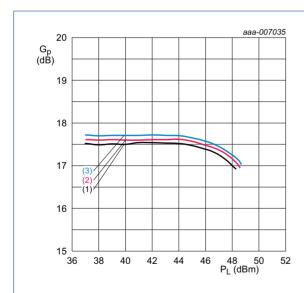


 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2622.5 MHz
- (2) f = 2655 MHz
- (3) f = 2687.5 MHz

Fig 14. Input return loss as a function of output power; typical values

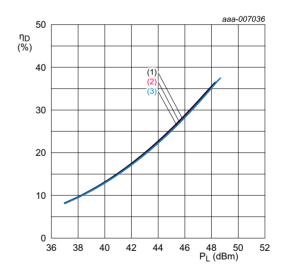
7.4.4 2-Carrier W-CDMA



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2625 MHz
- (2) f = 2655 MHz
- (3) f = 2685 MHz

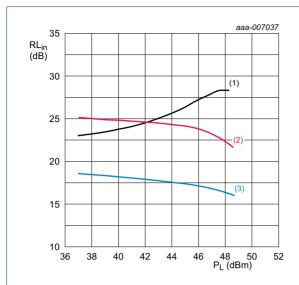
Fig 15. Power gain as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2625 MHz
- (2) f = 2655 MHz
- (3) f = 2685 MHz

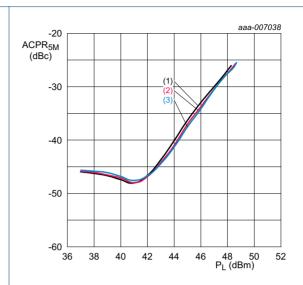
Fig 16. Drain efficiency as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2625 MHz
- (2) f = 2655 MHz
- (3) f = 2685 MHz

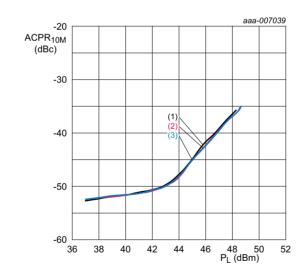
Fig 17. Input return loss as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

- (1) f = 2625 MHz
- (2) f = 2655 MHz
- (3) f = 2685 MHz

Fig 18. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 $V_{DS} = 32 \text{ V}; I_{Dq} = 1300 \text{ mA}.$

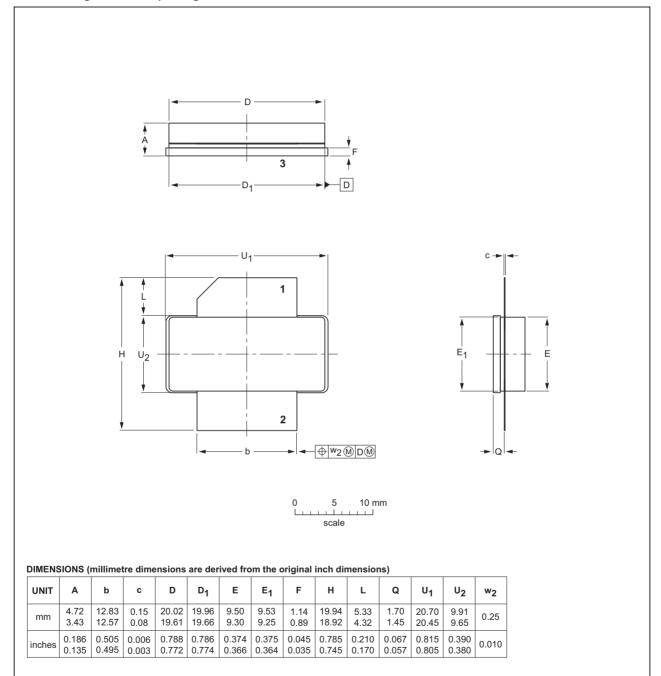
- (1) f = 2625 MHz
- (2) f = 2655 MHz
- (3) f = 2685 MHz

Fig 19. Adjacent channel power ratio (10 MHz) as a function of output power; typical values

8. Package outline

Earless flanged ceramic package; 2 leads

SOT502B



OUTLINE		REFER	RENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE	
SOT502B					07-05-09 12-05-02	

Fig 20. Package outline SOT502B

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BLF8G27LS-140#3	20150901	Product data sheet	-	BLF8G27LS-140 v.2			
Modifications:	guidelines o	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 					
BLF8G27LS-140 v.2	20130605	Product data sheet	-	BLF8G27LS-140 v.1			
BLF8G27LS-140 v.1	20130328	Objective data sheet	-	-			

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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BLF8G27LS-140

Power LDMOS transistor

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